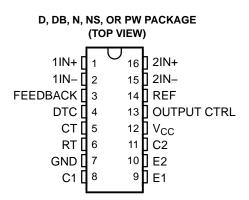


#### FEATURES

- Complete PWM Power-Control Circuitry
- Uncommitted Outputs for 200-mA Sink or Source Current
- Output Control Selects Single-Ended or Push-Pull Operation
- Internal Circuitry Prohibits Double Pulse at Either Output
- Variable Dead Time Provides Control Over Total Range
- Internal Regulator Provides a Stable 5-V Reference Supply With 5% Tolerance
- Circuit Architecture Allows Easy
  Synchronization



## DESCRIPTION

The TL494 incorporates all the functions required in the construction of a pulse-width-modulation (PWM) control circuit on a single chip. Designed primarily for power-supply control, this device offers the flexibility to tailor the power-supply control circuitry to a specific application.

The TL494 contains two error amplifiers, an on-chip adjustable oscillator, a dead-time control (DTC) comparator, a pulse-steering control flip-flop, a 5-V, 5%-precision regulator, and output-control circuits.

The error amplifiers exhibit a common-mode voltage range from -0.3 V to V<sub>CC</sub> -2 V. The dead-time control comparator has a fixed offset that provides approximately 5% dead time. The on-chip oscillator can be bypassed by terminating RT to the reference output and providing a sawtooth input to CT, or it can drive the common circuits in synchronous multiple-rail power supplies.

The uncommitted output transistors provide either common-emitter or emitter-follower output capability. The TL494 provides for push-pull or single-ended output operation, which can be selected through the output-control function. The architecture of this device prohibits the possibility of either output being pulsed twice during push-pull operation.

The TL494C is characterized for operation from 0°C to 70°C. The TL494I is characterized for operation from -40°C to 85°C.

		F	PACKAGED DEVICES	1)	
T <sub>A</sub>	SMALL OUTLINE (D)	PLASTIC DIP (N)	SMALL OUTLINE (NS)	SHRINK SMALL OUTLINE (DB)	THIN SHRINK SMALL OUTLINE (PW)
0°C to 70°C	TL494CD	TL494CN	TL494CNS	TL494CDB	TL494CPW
–40°C to 85°C	TL494ID	TL494IN	—	—	—

#### AVAILABLE OPTIONS

(1) The D, DB, NS, and PW packages are available taped and reeled. Add the suffix R to device type (e.g., TL494CDR).

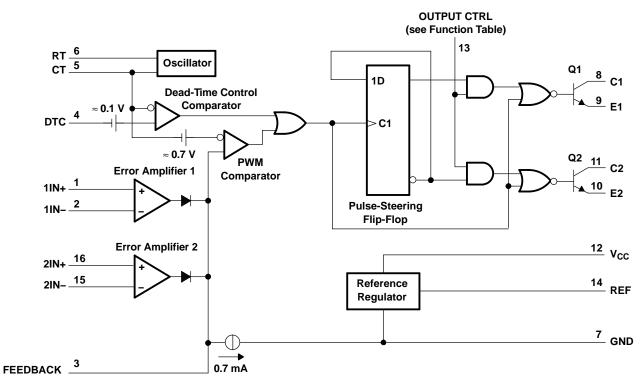


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

#### **FUNCTION TABLE**

INPUT TO OUTPUT CTRL	OUTPUT FUNCTION					
$V_I = GND$	Single-ended or parallel output					
$V_I = V_{ref}$	Normal push-pull operation					

## FUNCTIONAL BLOCK DIAGRAM



#### 2

## Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN MA	X UNIT
V <sub>CC</sub>	Supply voltage <sup>(2)</sup>		4	1 V
VI	Amplifier input voltage		V <sub>CC</sub> + 0	3 V
Vo	Collector output voltage		4	1 V
I <sub>O</sub>	Collector output current		25	0 mA
		D package	7	3
		DB package	8	2
$\theta_{JA}$	Package thermal impedance <sup>(3)(4)</sup>	N package	6	7 °C/W
		NS package	6	4
		PW package	10	8
	Lead temperature 1,6 mm (1/16 inch) from c	ase for 10 seconds	26	0°C
T <sub>stg</sub>	Storage temperature range		-65 15	0°C

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings (1) only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2)

All voltages are with respect to the network ground terminal. Maximum power disipation is a function of  $T_J(max)$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any allowable ambient temperatire is  $P_D = (T_J(max) - T_A)/\theta_{JA}$ . Operating at the absolute maximum  $T_J$  of 150°C can affect reliability. The package thermal impedance is calculated in accordance with JESD 51-7. (3)

(4)

## **Recommended Operating Conditions**

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		7	40	V
VI	Amplifier input voltage		-0.3	$V_{CC} - 2$	V
Vo	Collector output voltage			40	V
	Collector output current (each transistor)			200	mA
	Current into feedback terminal			0.3	mA
f <sub>OSC</sub>	Oscillator frequency		1	300	kHz
CT	Timing capacitor		0.47	10000	nF
R <sub>T</sub>	Timing resistor		1.8	500	kΩ
-	On aroting free oir temperature	TL494C	0	70	°C
IA	Operating free-air temperature	TL494I	-40	0 70	-U

# TL494 PULSE-WIDTH-MODULATION CONTROL CIRCUITS

SLVS074E-JANUARY 1983-REVISED FEBRUARY 2005

#### **Electrical Characteristics**

over recommended operating free-air temperature range,  $V_{CC} = 15 \text{ V}$ , f = 10 kHz (unless otherwise noted)

TRUMENTS www.ti.com

#### **Reference Section**

PARAMETER	TEST CONDITIONS <sup>(1)</sup>	TL494C, TL494I			
PARAMETER	TEST CONDITIONS(*)		TYP <sup>(2)</sup>	MAX	UNIT
Output voltage (REF)	I <sub>O</sub> = 1 mA	4.75	5	5.25	V
Input regulation	$V_{CC} = 7 V \text{ to } 40 V$		2	25	mV
Output regulation	$I_{O} = 1 \text{ mA to } 10 \text{ mA}$		1	15	mV
Output voltage change with temperature	$\Delta T_A = MIN$ to MAX		2	10	mV/V
Short-circuit output current <sup>(3)</sup>	REF = 0 V		25		mA

(1) For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

(2) All typical values, except for parameter changes with temperature, are at  $T_A = 25^{\circ}C$ .

(3) Duration of short circuit should not exceed one second.

## **Oscillator Section**

 $C_T = 0.01 \ \mu\text{F}, R_T = 12 \ \text{k}\Omega$  (see Figure 1)

PARAMETER	TEST CONDITIONS <sup>(1)</sup>	TL494C, TL49		
PARAMETER	TEST CONDITIONS()	MIN TYP <sup>(2)</sup>	MAX	UNIT
Frequency		10		kHz
Standard deviation of frequency <sup>(3)</sup>	All values of $V_{CC}$ , $C_T$ , $R_T$ , and $T_A$ constant	100		Hz/kHz
Frequency change with voltage	$V_{CC}$ = 7 V to 40 V, $T_A$ = 25°C	1		Hz/kHz
Frequency change with temperature <sup>(4)</sup>	$\Delta T_A = MIN \text{ to MAX}$		10	Hz/kHz

(1) For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

(2) All typical values, except for parameter changes with temperature, are at  $T_A = 25^{\circ}C$ .

(3) Standard deviation is a measure of the statistical distribution about the mean as derived from the formula:

$$\sigma = \sqrt{\frac{\sum_{n=1}^{N} (x_n - \overline{X})^2}{N - 1}}$$

(4) Temperature coefficient of timing capacitor and timing resistor are not taken into account.

#### **Error-Amplifier Section**

See Figure 2

	TEST CONDITIONS	TL494	TL494C, TL494I			
PARAMETER	TEST CONDITIONS	MIN	TYP <sup>(1)</sup>	MAX	UNIT	
Input offset voltage	V <sub>O</sub> (FEEDBACK) = 2.5 V		2	10	mV	
Input offset current	$V_O$ (FEEDBACK) = 2.5 V		25	250	nA	
Input bias current	V <sub>O</sub> (FEEDBACK) = 2.5 V		0.2	1	μA	
Common-mode input voltage range	$V_{CC} = 7 V \text{ to } 40 V$	-0.3 to V <sub>CC</sub> - 2			V	
Open-loop voltage amplification	$\Delta V_{O}$ = 3 V, $V_{O}$ = 0.5 V to 3.5 V, R <sub>L</sub> = 2 k $\Omega$	70	95		dB	
Unity-gain bandwidth	$V_{O}$ = 0.5 V to 3.5 V, $R_{L}$ = 2 k $\Omega$		800		kHz	
Common-mode rejection ratio	$\Delta V_{O} = 40 \text{ V}, \text{ T}_{A} = 25^{\circ}\text{C}$	65	80		dB	
Output sink current (FEEDBACK)	$V_{ID} = -15 \text{ mV} \text{ to} -5 \text{ V}, \text{ V} \text{ (FEEDBACK)} = 0.7 \text{ V}$	0.3	0.7		mA	
Output source current (FEEDBACK)	$V_{ID}$ = 15 mV to 5 V, V (FEEDBACK) = 3.5 V	-2			mA	

(1) All typical values, except for parameter changes with temperature, are at  $T_A = 25^{\circ}C$ .

## **Electrical Characteristics**

over recommended operating free-air temperature range,  $V_{CC}$  = 15 V, f = 10 kHz (unless otherwise noted)

#### **Output Section**

PARAMETER	2	TEST CONDITIONS	MIN	TYP <sup>(1)</sup>	MAX	UNIT
Collector off-state current		$V_{CE} = 40 \text{ V}, V_{CC} = 40 \text{ V}$		2	100	μΑ
Emitter off-state current		$V_{CC} = V_C = 40 \text{ V}, \text{ V}_E = 0$			-100	μΑ
Collector-emitter saturation voltage	Common emitter	$V_{\rm E} = 0, I_{\rm C} = 200  {\rm mA}$		1.1	1.3	V
	Emitter follower	$V_{O(C1 \text{ or } C2)} = 15 \text{ V}, \text{ I}_{E} = -200 \text{ mA}$		1.5	2.5	
Output control input current		$V_I = V_{ref}$			3.5	mA

(1) All typical values, except for temperature coefficient, are at  $T_A = 25^{\circ}C$ .

## **Dead-Time Control Section**

See Figure 1

PARAMETER	TEST CONDITIONS	MIN TYP <sup>(1)</sup>	MAX	UNIT
Input bias current (DEAD-TIME CTRL)	$V_1 = 0$ to 5.25 V	-2	-10	μA
Maximum duty cycle, each output	$V_{I}$ (DEAD-TIME CTRL) = 0, $C_{T}$ = 0.01 $\mu F,$ $R_{T}$ = 12 $k\Omega$	45		%
	Zero duty cycle	3	3.3	V
Input threshold voltage (DEAD-TIME CTRL)	Maximum duty cycle	0		v

(1) All typical values, except for temperature coefficient, are at  $T_A = 25^{\circ}C$ .

### **PWM Comparator Section**

See Figure 1

PARAMETER	TEST CONDITIONS	MIN	TYP <sup>(1)</sup>	MAX	UNIT
Input threshold voltage (FEEDBACK)	Zero duty cyle		4	4.5	V
Input sink current (FEEDBACK)	V (FEEDBACK) = $0.7 \text{ V}$	0.3	0.7		mA

(1) All typical values, except for temperature coefficient, are at  $T_A = 25^{\circ}C$ .

#### **Total Device**

PARAMETER	TEST CONDITION	IS	MIN TYP <sup>(1)</sup>	MAX	UNIT
Standby supply surrent	$R_{T} = V_{ref}$ ,	V <sub>CC</sub> = 15 V	6	10	mA
Standby supply current	All other inputs and outputs open	$V_{CC} = 40 V$	c,	15	IIIA
Average supply current	V <sub>I</sub> (DEAD-TIME CTRL) = 2 V, See Figure	1	7.5		mA

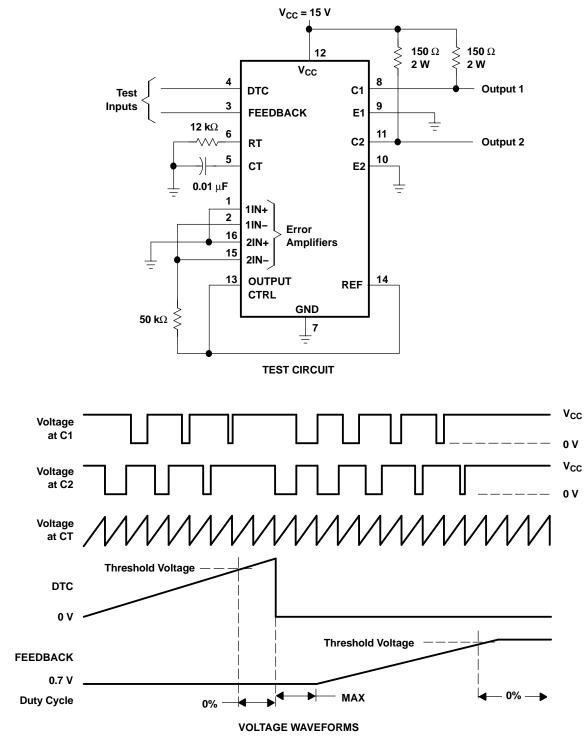
(1) All typical values, except for temperature coefficient, are at  $T_A = 25^{\circ}C$ .

## **Switching Characteristics**

 $T_A = 25^{\circ}C$ 

PARAMETER	TEST CONDITIONS	MIN TYP <sup>(1)</sup>	MAX	UNIT
Rise time	Common-emitter configuration, See Figure 3	100	200	ns
Fall time	Common-emilier comguration, See Figure 5	25	100	ns
Rise time	Emitter follower configuration, See Figure 4	100	200	ns
Fall time	Emitter-follower configuration, See Figure 4	40	100	ns

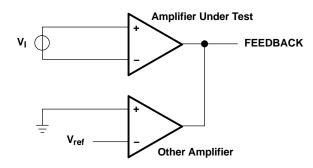
(1) All typical values, except for temperature coefficient, are at  $T_A = 25^{\circ}C$ .



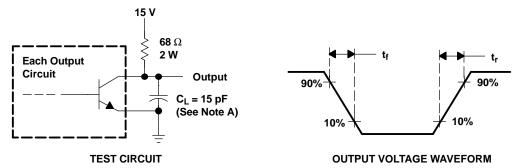
#### PARAMETER MEASUREMENT INFORMATION

Figure 1. Operational Test Circuit and Waveforms

#### PARAMETER MEASUREMENT INFORMATION

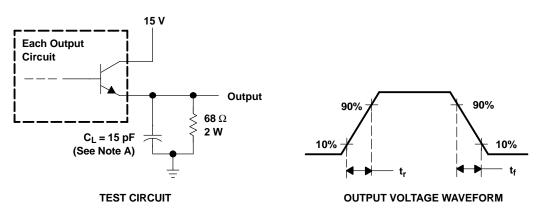


**Figure 2. Amplifier Characteristics** 



NOTE A: C<sub>L</sub> includes probe and jig capacitance.

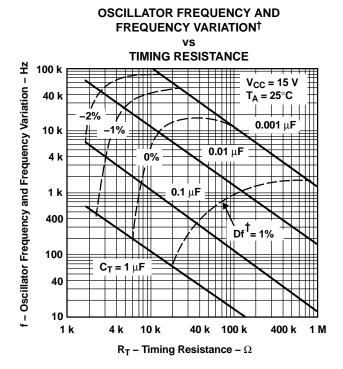




NOTE A:  $C_L$  includes probe and jig capacitance.

Figure 4. Emitter-Follower Configuration

#### **TYPICAL CHARACTERISTICS**



<sup>†</sup> Frequency variation ( $\Delta f$ ) is the change in oscillator frequency that occurs over the full temperature range.



AMPLIFIER VOLTAGE AMPLIFICATION vs FREQUENCY 100  $V_{CC} = 15 V$  $\Delta V_{O} = 3 V$ 90 A – Amplifier Voltage Amplification – dB T<sub>A</sub> = 25°C 80 70 60 50 40 30 20 10 0 10 1 100 1 k 10 k 100 k 1 M f - Frequency - Hz





11-Apr-2013

## PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
TL494CD	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL494C	Samples
TL494CDE4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL494C	Samples
TL494CDG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL494C	Samples
TL494CDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL494C	Samples
TL494CDRE4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL494C	Samples
TL494CDRG3	PREVIEW	SOIC	D	16		TBD	Call TI	Call TI	0 to 70	TL494C	
TL494CDRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL494C	Samples
TL494CJ	OBSOLETE	CDIP	J	16		TBD	Call TI	Call TI			
TL494CN	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TL494CN	Samples
TL494CNE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TL494CN	Samples
TL494CNSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL494	Samples
TL494CNSRG4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL494	Samples
TL494CPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	T494	Samples
TL494CPWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	T494	Samples
TL494CPWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	T494	Samples
TL494CPWLE	OBSOLETE	TSSOP	PW	16		TBD	Call TI	Call TI			
TL494CPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	T494	Samples
TL494CPWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	T494	Samples



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Orderable Device	Status	Package Type	•	Pins	•	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing		Qty	(2)		(3)		(4)	
TL494CPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	T494	Samples
TL494ID	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL494I	Samples
TL494IDE4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL494I	Samples
TL494IDG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL494I	Samples
TL494IDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL494I	Samples
TL494IDRE4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL494I	Samples
TL494IDRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL494I	Samples
TL494IN	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	TL494IN	Samples
TL494INE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	TL494IN	Samples
TL494MJ	OBSOLETE	CDIP	J	16		TBD	Call TI	Call TI	-55 to 125		
TL494MJB	OBSOLETE	CDIP	J	16		TBD	Call TI	Call TI	-55 to 125		

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW**: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)



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<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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## PACKAGE MATERIALS INFORMATION

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## TAPE AND REEL INFORMATION





## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TL494CDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TL494CDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TL494CDRG4	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TL494CPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TL494IDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TL494IDRG4	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1

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## PACKAGE MATERIALS INFORMATION

8-Apr-2013



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TL494CDR	SOIC	D	16	2500	333.2	345.9	28.6
TL494CDR	SOIC	D	16	2500	367.0	367.0	38.0
TL494CDRG4	SOIC	D	16	2500	333.2	345.9	28.6
TL494CPWR	TSSOP	PW	16	2000	367.0	367.0	35.0
TL494IDR	SOIC	D	16	2500	333.2	345.9	28.6
TL494IDRG4	SOIC	D	16	2500	333.2	345.9	28.6

J (R-GDIP-T\*\*) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



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# D (R-PDSO-G16) PLASTIC SMALL OUTLINE Stencil Openings (Note D) Example Board Layout (Note C) –16x0,55 -14x1,27 -14x1,27 16x1,50 5,40 5.40 Example Non Soldermask Defined Pad Example Pad Geometry (See Note C) 0,60 .55 Example 1. Solder Mask Opening (See Note E) -0,07 All Around

NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.  $\beta$ . This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



# PW (R-PDSO-G16)

# PLASTIC SMALL OUTLINE



- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



## MECHANICAL DATA

## PLASTIC SMALL-OUTLINE PACKAGE

#### 0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 $\bigcirc$ Gage Plane ₽ 0,25 7 1 1,05 0,55 0°-10° Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS \*\* 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G\*\*)

**14-PINS SHOWN** 

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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